EAST Search History

EAST Search History (Prior Art)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	16921	("TFT" or "thin film transistor") with data and gate and (electrode or conductor) and (pixel or ITO)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:27
S2	9	"6040882"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:27
S3	2	"20020008898"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:28
S4	2	"20030095223"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:29
S5	36	"5767926"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:29
S6	2	"20030020853"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:30
S7	4241	257/59	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:30

S8	2	"20060060849"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:30
S9	894	NMOS and S1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:45
S10	378	S9 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 09:45
S11	2	"20020008898"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:28
S12	4	"second common electrode" and S10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:40
S13	16	"second common electrode" and S7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:43
S14	9	S13 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:43
S15	276	"second common electrode" and S1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:44

S16	76	S15 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:44
S17	69	S16 not "samsung"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:45
S18	16921	("TFT" or "thin film transistor") with data and gate and (electrode or conductor) and (pixel or ITO)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 10:54
S19	2	"20040129937"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 13:24
S20	2	"20070012914"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 13:25
S21	73	"6414385"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/16 13:50
S22	2	("6414385").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/01/16 13:50
S23	20	"6573560"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/16 06:02

S24	3	"7045858"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/16 06:06
S25	9	"5825069"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/16 06:07
S26	17	"1139759"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/16 06:18
S27	1	"11396759"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/16 06:18
S28	360	(second adj (tft "thin film transistor")) same ((second) adj (pixel or reflect\$3 or transmissi \$3)) with (electrode)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 09:21
S29	63	S28 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 09:21
S30	20	("20010026343" "20020008898" "20020105614" "20030020853" "20030095223" "20030164500" "4678282" "6040882" "6195140" "6549258").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 09:22
S31	63	S29 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 09:22

S 32	20	S30 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 09:22
S33	3	("5164851" "5818407").PN. OR ("6791633").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/10 15:37
S34	7	("4776673" "6172729" "6449025" "6462798" "6590628").PN. OR ("7016006").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/10 15:40
S35		("20010001567" "4581608" "4728175" "4937566" "4978203" "5249070" "5517342" "5574582" "5608556" "5623354" "5666179" "5668650" "5673092" "5694185" "5737051" "5777701" "5796456" "5889569" "6091466" "6215542" "6285431" "6300996").PN. OR ("6462798").URPN.	US-PGPUB; USPAT; USOCR	OR		2009/08/10 15:42
S 36	37	S35 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/10 15:47
S37	83	("4068020" "4103297" "4239346" "4333794" "4365013" "4378417" "4431271" "4582395" "4591892" "4597160" "4621260" "4680580" "4740829" "4773737" "4775861" "4778773" "4818077" "4860069" "4862237" "4888305" "4891330" "4897360" "4938565" "4949141"	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/10 16:07

S40	26	("20020084459" "20030117560" "20040031991" "20040066472" "20040125260" "20040125302" "20050095757" "20060001027" "5398127" "5854665" "6064451" "6088078" "6091472" "6128061" "6154266" "6211937" "6256081" "6344889" "6466290" "6738110" "6906770" "6921917" "6933997" "6946680" "6975367").PN. OR ("7341895").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/10
S41	1	"10539678"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/11 11:30
S42	654	257/223	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/11 13:59
S43	113	257/227	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/11 13:59
S44	2069	257/291	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/11 13:59
S45	23	257/e29.202	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/11 13:59

S46	4306	((second) adj ("TFT" or "thin film transistor"))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:18
S47	16354	((second adj pixel) or ((reflecti\$3) near (electrode or conduct \$3 or metal)) and ((transmissive) near (electrode or conduct \$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:21
S48	16259	(second adj pixel) or ((reflective) near (electrode or conduct \$3 or metal)) and ((transmissive) near (electrode or conduct \$3 or metal))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:22
S 49	16259	(second adj pixel) or (((reflective) near (electrode or conduct \$3 or metal)) and ((transmissive) near (electrode or conduct \$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:22
S50	724	S49 and S46	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:23
S51	1424	(((reflective) near (electrode or conduct \$3 or metal)) and ((transmissive) near (electrode or conduct \$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:23
S52	835	(((reflective) adj (electrode or conduct \$3 or metal)) and ((transmissive) adj (electrode or conduct \$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:24
S53	27	S52 and S46	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:24

S54	2	"20060060849"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:25
S55	6799	(((reflective) with (electrode or conduct \$3 or metal)) and ((transmissive) with (electrode or conduct \$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:26
S56	127	S55 and S46	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:26
S57	0	S53 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:26
S58	26	\$56 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:26
S59	697	((second) adj ("TFT" or "thin film transistor")) and ((second adj pixel) or ((second adj reflectriv \$3) adj (electrode or conduct\$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:43
S60	701	((second) adj ("TFT" or "thin film transistor")) and ((second adj pixel) or ((second adj reflectiv \$3) adj (electrode or conduct\$3 or metal)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:43
S61	697	((second) adj ("TFT" or "thin film transistor")) and (second adj pixel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:44

S62	446	((wir\$3 or electrode or conduct\$3) with (capacit\$3)) and \$60	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:45
S63	442	((wir\$3 or electrode or conduct\$3) with (capacit\$3)) and \$61	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:45
S64	446	S62 or S63	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:46
S65	76	S64 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:46
S66	497	((wir\$3 or electrode or conduct\$3) and (capacit\$3)) and \$61	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:47
S67	501	((wir\$3 or electrode or conduct\$3) and (capacit\$3)) and \$60	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:47
S68	501	S66 or S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:47
S69	89	S68 and @ad < "20021221"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/03/09 10:47

S70	89	S65 or S69	US-PGPUB;	OR	ON	2010/03/09
			USPAT;			10:48
			USOCR; FPRS;			
			EPO; JPO;			
			DERWENT;			
			IBM_TDB			

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